

**Features** 

Internal control latches and address decoder

Short set-up and hold times

Wide operating voltage: 4.5V to 13.2V

12Vpp analog signal capability

•  $R_{ON}$  65 $\Omega$  max. @  $V_{DD}$ =12V, 25 $^{\circ}$ C

•  $\Delta R_{ON} \le 10\Omega$  @  $V_{DD}=12V$ ,  $25^{\circ}C$ 

Full CMOS switch for low distortion

Minimum feedthrough and crosstalk

Separate analog and digital reference supplies

Low power consumption ISO-CMOS technology

## **Applications**

- Key systems
- PBX systems
- Mobile radio
- Test equipment/instrumentation
- Analog/digital multiplexers
- · Audio/Video switching

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#### **Ordering Information**

MT8806AE 24 Pin Plastic DIP MT8806AP 28 Pin PLCC -40° to 85°C

## **Description**

The Zarlink MT8806 is fabricated in Zarlink's ISO-CMOS technology providing low power dissipation and high reliability. The device contains a 8 x 4 array of crosspoint switches along with a 5 to 32 line decoder and latch circuits. Any one of the 32 switches can be addressed by selecting the appropriate five address bits. The selected switch can be turned on or off by applying a logical one or zero to the DATA input.  $V_{SS}$  is the ground reference of the digital inputs. The range of the analog signal is from  $V_{DD}$  to  $V_{EE}$ . Chip Select (CS) allows the crosspoint array to be cascaded for matrix expansion.

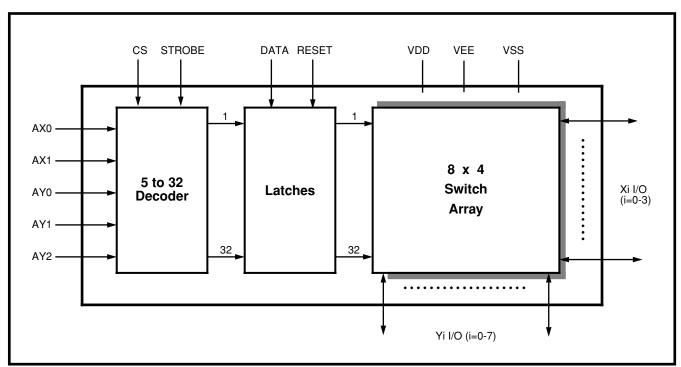


Figure 1 - Functional Block Diagram

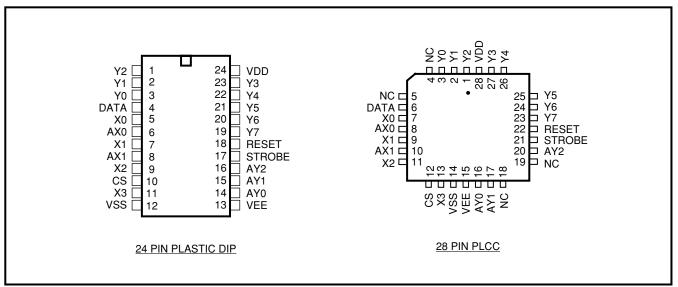


Figure 2 - Pin Connections

## **Pin Description**

		Ì	
Piı	n #	Name	Description
PDIP	PLCC		2000p.iio.ii
1-3	1-3	Y2-Y0	<b>Y2-Y0 Analog (Inputs/Outputs):</b> these are connected to the Y2-Y0 columns of the switch array.
4	6	DATA	<b>DATA (Input)</b> : a logic high input will turn on the selected switch and a logic low will turn off the selected switch. Active High.
5	7	X0	X0 Analog (Input/Output): this is connected to the X0 row of the switch array.
6	8	AX0	X0 Address Line (Input).
7	9	X1	X1 Analog (Input/Output): this is connected to the X1 row of the switch array.
8	10	AX1	X1 Address Line (Input).
9	11	X2	X2 Analog (Input/Output): this is connected to the X2 row of the switch array.
10	12	CS	Chip Select (Input): this is used to select the device. Active High.
11	13	Х3	X3 Analog (Input/Output): this is connected to the X3 row of the switch array.
12	14	V <sub>SS</sub>	Digital Ground Reference.
13	15	V <sub>EE</sub>	Negative Power Supply.
14-16	16,17, 20	AY0-AY2	Y0 -Y2 Address Lines (Inputs).
17	21	STROBE	STROBE (Input): enables function selected by address and data. Address must be stable before STROBE goes high and DATA must be stable on the falling edge of the STROBE. Active High.
18	22	RESET	<b>Master RESET (Input):</b> this is used to turn off all switches regardless of the condition of CS. Active High.
19-23	23-27	Y7-Y3	Y7-Y3 Analog (Inputs/Outputs): these are connected to the Y7-Y3 columns of the switch array.
24	28	VDD	Positive Power Supply.
	4, 5, 18, 19	NC	No Connect.

## **Functional Description**

The MT8806 is an analog switch matrix with an array size of 8 x 4. The switch array is arranged such that there are 8 columns by 4 rows. The columns are referred to as the Y inputs/outputs and the rows are the X inputs/outputs. The crosspoint analog switch array will interconnect any X I/O with any Y I/O when turned on and provide a high degree of isolation when turned off. The control memory consists of a 32 bit write only RAM in which the bits are selected by the address inputs (AY0-AY2, AX0 & AX1). Data is presented to the memory on the DATA input. Data is asynchronously written into memory whenever both the CS (Chip Select) and the STROBE inputs are high and is latched on the falling edge of STROBE. A logical "1" written into a memory cell turns the corresponding crosspoint switch on and a logical "0" turns the crosspoint off. Only the crosspoint switches corresponding to the addressed memory location are altered when data is written into memory. The remaining switches retain their previous states. Any combination of X and Y inputs/ outputs can be interconnected by establishing appropriate patterns in the control memory. A logical "1" on the RESET input will asynchronously return all memory locations to logical "0" turning off all crosspoint switches regardless of whether CS is high or low. Two voltage reference pins (V<sub>SS</sub> and V<sub>FF</sub>) are provided for the MT8806 to enable switching of negative analog signals. The range for digital signals is from V<sub>DD</sub> to V<sub>SS</sub> while the range for analog signals is from  $V_{DD}$  to  $V_{EE}$ .  $V_{SS}$  and  $V_{EE}$  pins can be tied together if a single voltage reference is needed.

## **Address Decode**

The five address inputs along with the STROBE and CS (Chip Select) inputs are logically ANDed to form an enable signal for the resettable transparent latches. The DATA input is buffered and is used as the input to all latches. To write to a location, RESET must be low and CS must go high while the address and data are set up. Then the STROBE input is set high and then low causing the data to be latched. The data can be changed while STROBE is high, however, the corresponding switch will turn on and off in accordance with the DATA input. DATA must be stable on the falling edge of STROBE in order for correct data to be written to the latch.

# $\textbf{Absolute Maximum Ratings*-} \ \textit{Voltages are with respect to V}_{\text{EE}} \ \textit{unless otherwise stated}.$

	Parameter	Symbol	Min	Max	Units
1	Supply Voltage	$V_{DD}$ $V_{SS}$	-0.3 -0.3	15.0 V <sub>DD</sub> +0.3	V
2	Analog Input Voltage	V <sub>INA</sub>	-0.3	V <sub>DD</sub> +0.3	V
3	Digital Input Voltage	V <sub>IN</sub>	V <sub>SS</sub> -0.3	V <sub>DD</sub> +0.3	V
4	Current on any I/O Pin	I		±15	mA
5	Storage Temperature	T <sub>S</sub>	-65	+150	°C
6	Package Power Dissipation PLASTIC DIP	P <sub>D</sub>		0.6	W

Exceeding these values may cause permanent damage. Functional operation under these conditions is not implied.

## Recommended Operating Conditions - Voltages are with respect to V<sub>EE</sub> unless otherwise stated.

	Characteristics	Sym	Min	Тур	Max	Units	Test Conditions
1	Operating Temperature	T <sub>O</sub>	-40	25	85	°C	
2	Supply Voltage	V <sub>DD</sub> V <sub>SS</sub>	4.5 V <sub>EE</sub>		13.2 V <sub>DD</sub> -4.5	V V	
3	Analog Input Voltage	V <sub>INA</sub>	V <sub>EE</sub>		$V_{DD}$	V	
4	Digital Input Voltage	V <sub>IN</sub>	$V_{SS}$		$V_{DD}$	V	

## DC Electrical Characteristics<sup>†</sup>- Voltages are with respect to V<sub>EE</sub>=V<sub>SS</sub>=0V, V<sub>DD</sub> =12V unless otherwise stated.

	Characteristics	Sym	Min	Typ <sup>‡</sup>	Max	Units	Test Conditions
1	Quiescent Supply Current	I <sub>DD</sub>		1	100	μΑ	All digital inputs at $V_{IN}=V_{SS}$ or $V_{DD}$
				0.4	1.5	mA	All digital inputs at $V_{IN}$ =2.4 + $V_{SS}$ ; $V_{SS}$ =7.0V
				5	15	mA	All digital inputs at V <sub>IN</sub> =3.4V
2	Off-state Leakage Current (See G.9 in Appendix)	l <sub>OFF</sub>		±1	±500	nA	$IV_{Xi} - V_{Yj}I = V_{DD} - V_{EE}$ See Appendix, Fig. A.1
3	Input Logic "0" level	V <sub>IL</sub>			0.8+V <sub>S</sub> S	V	V <sub>SS</sub> =7.5V; V <sub>EE</sub> =0V
4	Input Logic "1" level	V <sub>IH</sub>	2.0+V <sub>SS</sub>			V	$V_{SS} = 6.5V; V_{EE} = 0V$
5	Input Logic "1" level	V <sub>IH</sub>	3.3			V	
6	Input Leakage (digital pins)	I <sub>LEAK</sub>		0.1	10	μΑ	All digital inputs at $V_{IN} = V_{SS}$ or $V_{DD}$

# $\textbf{DC Electrical Characteristics-Switch Resistance} \ \ \text{-} \ \text{V}_{\text{DC}} \ \text{is the external DC offset applied at the analog I/O pins.}$

	Characteristics	Sym	25	5°C	70	)°C	85	5°C	Units	Test Conditions
			Тур	Max	Тур	Max	Тур	Max		
1		R <sub>ON</sub>	45 55 120	65 75 185		75 85 215		80 90 225	Ω Ω Ω	$V_{SS}=V_{EE}=0V, V_{DC}=V_{DD}/2,$ $IV_{Xi}-V_{Yj}I=0.4V$ See Appendix, Fig. A.2
2	Difference in on-state resistance between two switches (See G.4 in Appendix)	ΔR <sub>ON</sub>	5	10		10		10	Ω	$\begin{split} &V_{DD}{=}12\text{V, }V_{SS}{=}V_{EE}{=}0,\\ &V_{DC}{=}V_{DD}/2,\\ &IV_{Xi}{-}V_{Yj}I=0.4\text{V}\\ &\text{See Appendix, Fig. A.2} \end{split}$

<sup>†</sup> DC Electrical Characteristics are over recommended temperature range. ‡ Typical figures are at 25°C and are for design aid only; not guaranteed and not subject to production testing.

### AC Electrical Characteristics<sup>†</sup> - Crosspoint Performance - Voltages are with respect to V<sub>DD</sub>=5V, V<sub>SS</sub>=0V, V<sub>EE</sub>=-7V, unless otherwise stated.

	Characteristics	Sym	Min	Typ <sup>‡</sup>	Max	Units	Test Conditions
1	Switch I/O Capacitance	C <sub>S</sub>		20		pF	f=1 MHz
2	Feedthrough Capacitance	C <sub>F</sub>		0.2		pF	f=1 MHz
3	Frequency Response Channel "ON" 20LOG(V <sub>OUT</sub> /V <sub>Xi</sub> )=-3dB	F <sub>3dB</sub>		45		MHz	Switch is "ON"; $V_{INA} = 2Vpp$ sinewave; $R_L = 1k\Omega$ See Appendix, Fig. A.3
4	Total Harmonic Distortion (See G.5, G.6 in Appendix)	THD		0.01		%	Switch is "ON"; $V_{INA} = 2Vpp$ sinewave f= 1kHz; $R_L$ =1k $\Omega$
5	Feedthrough Channel "OFF" Feed.=20LOG (V <sub>OUT</sub> /V <sub>Xi</sub> ) (See G.8 in Appendix)	FDT		-95		dB	All Switches "OFF"; $V_{INA}$ = 2Vpp sinewave; $f$ = 1kHz; $R_L$ = 1k $\Omega$ . See Appendix, Fig. A.4
6	Crosstalk between any two channels for switches Xi-Yi and	X <sub>talk</sub>		-45		dB	$V_{INA}$ =2Vpp sinewave f= 10MHz; $R_L = 75\Omega$ .
	Xj-Yj.			-90		dB	$V_{INA}$ =2Vpp sinewave f= 10kHz; R <sub>L</sub> = 600 $\Omega$ .
	Xtalk=20LOG (V <sub>Yj</sub> /V <sub>Xi</sub> ).  (See G.7 in Appendix).			-85		dB	$V_{INA}$ =2Vpp sinewave f= 10kHz; R <sub>L</sub> = 1k $\Omega$ .
	(SSS S.I. III Appointain).			-80		dB	$V_{INA}$ =2Vpp sinewave f= 1kHz; R <sub>L</sub> = 10k $\Omega$ . Refer to Appendix, Fig. A.5 for test circuit.
7	Propagation delay through switch	t <sub>PS</sub>			30	ns	$R_L=1k\Omega$ ; $C_L=50pF$

## AC Electrical Characteristics<sup>†</sup> - Control and I/O Timings- Voltages are with respect to V<sub>DD</sub>=5V, V<sub>SS</sub>=0V, V<sub>EE</sub>=-7V, unless otherwise stated.

	Characteristics	Sym	Min	Typ <sup>‡</sup>	Max	Units	Test Conditions
1	Control Input crosstalk to switch (for CS, DATA, STROBE, Address)	CX <sub>talk</sub>		30		mVpp	$V_{\text{IN}}$ =3V squarewave; $R_{\text{IN}}$ =1k $\Omega$ , $R_{\text{L}}$ =10k $\Omega$ . See Appendix, Fig. A.6
2	Digital Input Capacitance	C <sub>DI</sub>		10		pF	f=1MHz
3	Switching Frequency	F <sub>O</sub>			20	MHz	
4	Setup Time DATA to STROBE	t <sub>DS</sub>	10			ns	$R_L=1k\Omega$ , $C_L=50pF$ )
5	Hold Time DATA to STROBE	t <sub>DH</sub>	10			ns	$R_L=1k\Omega$ , $C_L=50pF$ )
6	Setup Time Address to STROBE	t <sub>AS</sub>	10			ns	$R_L=1k\Omega$ , $C_L=50pF$ )
7	Hold Time Address to STROBE	t <sub>AH</sub>	10			ns	$R_L=1k\Omega$ , $C_L=50pF$ )
8	Setup Time CS to STROBE	t <sub>CSS</sub>	10			ns	$R_L=1k\Omega$ , $C_L=50pF$ )
9	Hold Time CS to STROBE	t <sub>CSH</sub>	10			ns	$R_L=1k\Omega$ , $C_L=50pF$ )
10	STROBE Pulse Width	t <sub>SPW</sub>	20			ns	$R_L=1k\Omega$ , $C_L=50pF$ )
11	RESET Pulse Width	t <sub>RPW</sub>	40			ns	$R_L=1k\Omega$ , $C_L=50pF$ )
12	STROBE to Switch Status Delay	t <sub>S</sub>		40	100	ns	$R_L=1k\Omega$ , $C_L=50pF$ )
13	DATA to Switch Status Delay	t <sub>D</sub>		50	100	ns	$R_L=1k\Omega$ , $C_L=50pF$ )
14	RESET to Switch Status Delay	t <sub>R</sub>		35	100	ns	$R_L=1k\Omega$ , $C_L=50pF$ )

<sup>†</sup> Timing is over recommended temperature range. See Fig. 3 for control and I/O timing details.

‡ Typical figures are at 25°C and are for design aid only; not guaranteed and not subject to production testing.

Crosstalk measurements are for Plastic DIPS only, crosstalk values for PLCC packages are approximately 5dB better.

<sup>†</sup> Timing is over recommended temperature range. See Fig. 3 for control and I/O timing details.

Digital Input rise time (tr) and fall time (tf) = 5ns.

‡ Typical figures are at 25°C and are for design aid only; not guaranteed and not subject to production testing.

) Refer to Appendix, Fig. A.7 for test circuit.

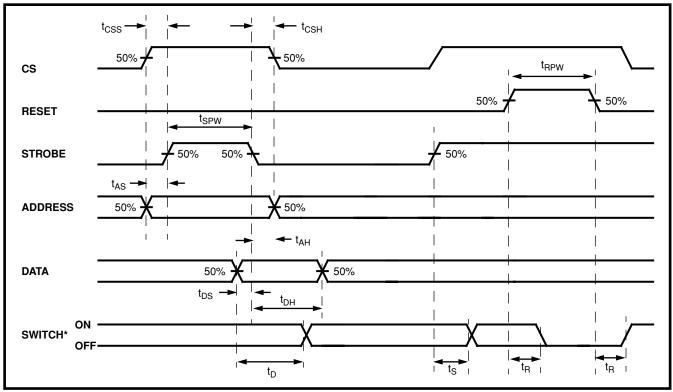
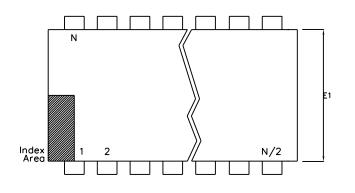


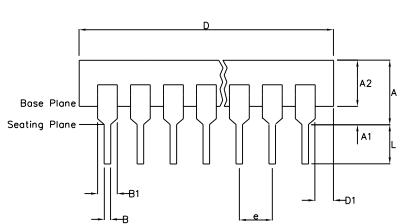
Figure 3 - Control Memory Timing Diagram

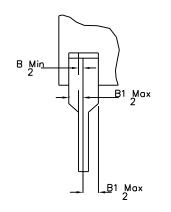
<sup>\*</sup> See Appendix, Fig. A.7 for switching waveform

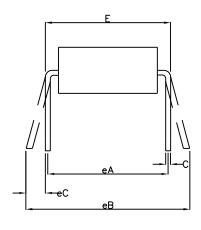
AX0	AX1	AY0	AY1	AY2	Connection
0	0	0	0	0	X0-Y0
0	0	1	0	0	X0-Y1
0	0	0	1	0	X0-Y2
0	0	1	1	0	X0-Y3
0	0	0	0	1	X0-Y4
0	0	1	0	1	X0-Y5
0	0	0	1	1	X0-Y6
0	0	1	1	1	X0-Y7
1	0	0	0	0	X1-Y0 ↓ ↓
1	0	1	1	1	X1-Y7
0	1	0	0	0	X2-Y0 ↓ ↓
0	1	1	1	1	X2-Y7
1	1.	O	0	0	X3-Y0 ↓ ↓
1	1	1	1	1	X3-Y7

Table 1. Address Decode Truth Table









	Min	Max	Min	Max			
	mm	mm	Inches	Inches			
Α		6.35		0.250			
A1	0.38		0.015				
A2	3.18	4.95	0.125	0.195			
В	0.36	0.56	0.014	0.022			
B1	0.76	1.78	0.030	0.070			
С	0.20	0.38	0.008	0.015			
D	29.21	32.77	1.150	1.290			
D1	0.13		0.005				
E	15.24	15.88	0.600	0.625			
E1	12.32	14.73	0.485	0.580			
е	2.54	BSC	0.100	BSC			
eА	15.24	BSC	0.600	) BSC			
eВ		17.78		0.700			
L	2.92	5.08	0.115	0.200			
N	2	4	2	4			
Confo	Conforms to Jedec MS-011AA ISS.B						

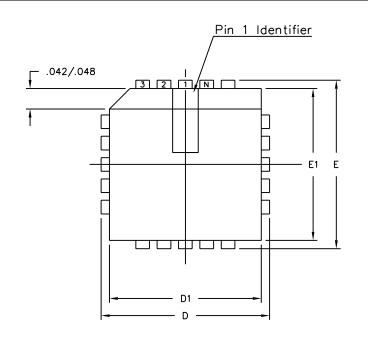
#### Notes:

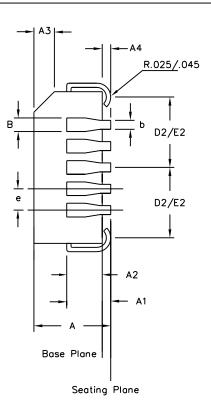
1. Controlling Dimensions are in inches
2. Dimension A, A1 and L are measured with the package seated in the Seating Plane
3. Dimensions D & E1 do not include mould flash or protrusions. Mould flash or protrusion shall not exceed 0.010 inch.
4. Dimensions E & eA are measured with leads constrained to be perpendicular to plane T.
5. Dimensions eB & eC are measured at the lead tips with the leads unconstrained; eC must be zero or greater.

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	Package Code
Previous package codes	Package Outline for 24 lead PDIP
DP / E	24 lead PDIP
	GPD00071





	Control Di	imensions	Altern. Di	mensions			
Symbol	in inc	hes	in milli	metres			
	MIN	MAX	MIN	MAX			
Α	0.165	0.180	4.19	4.57			
A1	0.090	0.120	2.29	3.05			
A2	0.062	0.083	1.57	2.11			
А3	0.042	0.056	1.07	1.42			
A4	0.020	_	0.51	-			
D	0.485	0.495	12.32	12.57			
D1	0.450	0.456	11.43	11.58			
D2	0.191	0.219	4.85	5.56			
E	0.485	0.495	12.32	12.57			
E1	0.450	0.456	11.43	11.58			
E2	0.191	0.219	4.85	5.56			
В	0.026	0.032	0.66	0.81			
b	0.013	0.021	0.33	0.53			
е	0.050	BSC	1.27	BSC			
	Pin features						
ND	7						
NE	7						
N	28						
Note	·	Square					
Confor	ms to J	EDEC MS	-018AB	Iss. A			

#### Notes:

- 1. All dimensions and tolerances conform to ANSI Y14.5M-1982
- 2. Dimensions D1 and E1 do not include mould protrusions.
  Allowable mould protrusion is 0.010" per side. Dimensions D1 and E1 include mould protrusion mismatch and are determined at the parting line, that is D1 and E1 are measured at the extreme material condition at the upper or lower parting line.
- 3. Controlling dimensions in Inches.
- 4. "N" is the number of terminals.
- 5. Not To Scale
- 6. Dimension R required for 120° minimum bend.

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ISSUE	1	2	3		ZARLINK SEMICONDUCTOR	Previous package codes	Package Outline for 28 lead PLCC
ACN	5958	207469	212422				
DATE	15Aug94	10Sep99	22Mar02			,	
APPRD.							GPD00002



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